



TECH PUBLIC

台电电子

TP1001S3

HIGH-SIDE CURRENT MONITOR

Features

- Low cost, accurate high-side current sensing
- Output voltage scaling
- Up to 2.5V sense voltage
- 2.5V to 20V supply range
- 4 μ A quiescent current
- 1% typical accuracy

Applications

- Battery chargers
- Smart battery packs
- DC motor control
- Over current monitor
- Power management
- Level translating
- Programmable current source

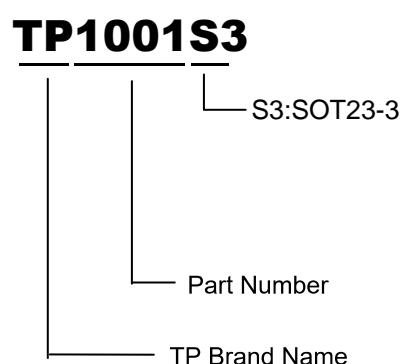
General Description

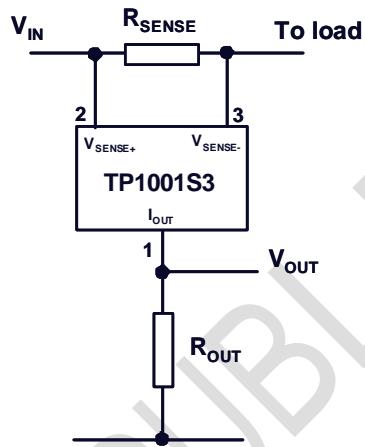
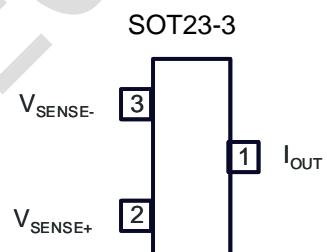
The TP1001S3 is a high side current sense monitor. Using this device eliminates the need to disrupt the ground plane when sensing a load current.

It takes a high side voltage developed across a current shunt resistor and translates it into a proportional output current. A user defined output resistor scales the output current into a ground-referenced voltage.

The wide input voltage range of 20V down to as low as 2.5V make it suitable for a range of applications. A minimum operating current of just 4 μ A, combined with a SOT23 package make it a unique solution for portable battery equipment.

Ordering Information



TYPICAL APPLICATION**PIN CONFIGURATION**

Pin Name	Pin Function
V _{SENSE+}	Connection to supply voltage
V _{SENSE-}	Connection to load
I _{OUT}	Output current, proportional to measured current

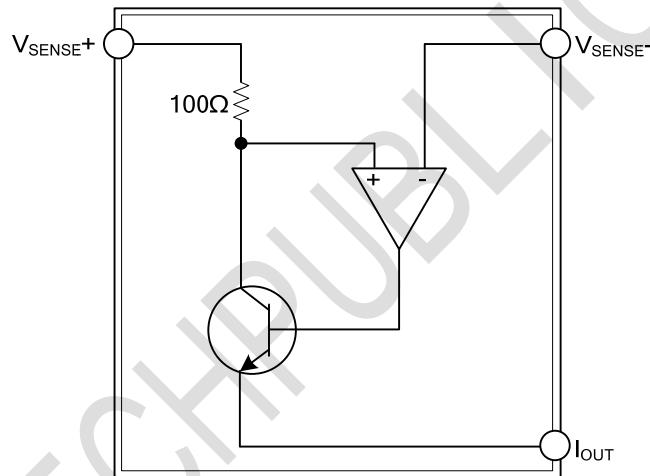


Absolute Maximum Rating ($T_A=25^\circ\text{C}$ unless otherwise noted)

Description	Rating	Unit
Voltage on any pin (relative to I_{OUT})	-0.6 to 20	V
Continous output current, I_{OUT}	25	mA
Continuous sense voltage, V_{SENSE}^{\dagger}	-0.5 to +5	V
Operating temperature, T_A	-40 to 85	$^\circ\text{C}$
Storage temperature	-55 to 125	$^\circ\text{C}$
Package power dissipation @ $T_A = 25^\circ\text{C}$ (Derate to zero @ 125°C)	450 SM8	mW W

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Conditions	Limits			Units
			Min	Typ	Max	
V_{IN}	V_{CC} range		2.5		20	V
I_{OUT}^{\dagger}	Output Current	$V_{SENSE} = 0\text{V}$ $V_{SENSE} = 10\text{mV}$ $V_{SENSE} = 100\text{mV}$ $V_{SENSE} = 200\text{mV}$ $V_{SENSE} = 1\text{V}$	1 90 0.975 1.95 9.6	4 104 1.002 2.0 9.98	15 120 1.025 2.05 10.2	μA μA mA mA mA
V_{SENSE}^{\dagger}	Sense Voltage		0		2500	mV
I_{SENSE-}	V_{SENSE} - Input Current				100	nA
Acc	Accuracy	$R_{SENSE} = 0.1\Omega$ $V_{SENSE} = 200\text{mV}$	-2.5		2.5	%
G_M	Transconductance, I_{OUT}/V_{SENSE}			10000		$\mu\text{A/V}$
BW	Bandwidth	$V_{SENSE(\text{DC})} = 10\text{mV}$, RF $P_{IN} = -40\text{dBm}^{\ddagger}$ $V_{SENSE(\text{DC})} = 100\text{mV}$, RF $P_{IN} = -20\text{dBm}^{\ddagger}$		300 2		kHz MHz

BLOCK DIAGRAM

Package information

SOT23-3

